



肖特基桥式整流器 Schottky Bridge Rectifier

■特征 Features

- I_o 1.0A
- V_{RRM} 20V~100V
- 肖特基芯片
Schottky chip
- 耐正向浪涌电流能力高
High surge forward current capability
- 低正向电压
Low VF

■用途 Applications

- 作一般电源单相桥式整流用
General purpose 1 phase Bridge rectifier applications

■极限值（绝对最大额定值）

Limiting Values (Absolute Maximum Rating)

| 参数名称 Item | 符号 Symbol | 单位 Unit | 条件 Conditions | MBSK | | | | |
|---|--------------|------------|--|---|-----|-----|-----|-----------|
| | | | | 12S | 14S | 16S | 18S | 110S |
| 反向重复峰值电压 Repetitive Peak Reverse Voltage | V_{RRM} | V | | 20 | 40 | 60 | 80 | 100 |
| 平均整流输出电流 Average Rectified Output Current | I_o | A | 60Hz正弦波, 电阻负载, $T_a=25^\circ C$ | 安装在氧化铝基板上 On alumina substrate | | | | 1.0 |
| | | | 60Hz sine wave, R-load, $T_a=25^\circ C$ | 安装在玻璃-环氧基板上 On glass-epoxy substrate | | | | 0.8 |
| 正向(不重复)浪涌电流 Surge(Non-repetitive)Forward Current | I_{FSM} | A | 60Hz正弦波, 一个周期, $T_j=25^\circ C$ 60Hz sine wave, 1 cycle, $T_j=25^\circ C$ | | | | | 40 |
| 正向浪涌电流的平方对时间 浪涌持续时间的积分值 Current Squared Time | I^2t | A^2S | 1ms $\leq t < 8.3ms$ $T_j=25^\circ C$, 单个二极管 1ms $\leq t < 8.3ms$ $T_j=25^\circ C$, Rating of per diode | | | | | 6.6 |
| 存储温度 Storage Temperature | T_{stg} | $^\circ C$ | | | | | | -55 ~+150 |
| 结温 Junction Temperature | T_j | $^\circ C$ | | | | | | -55 ~+150 |

■电特性 ($T_a=25^\circ C$ 除非另有规定)Electrical Characteristics ($T_a=25^\circ C$ Unless otherwise specified)

| 参数名称 Item | 符号 Symbol | 单位 Unit | 测试条件 Test Condition | 最大值 Max | | |
|--------------------------------|------------------|--------------|---|--------------------------------|--------------------------------|--------------------------|
| | | | | 正向峰值电压 Peak Forward Voltage | 反向峰值电流 Peak Reverse Current | 热阻 Thermal Resistance |
| 正向峰值电压 Peak Forward Voltage | V_{FM} | V | $I_{FM}=0.5A$, 脉冲测试, 单个二极管的额定值 $I_{FM}=0.5A$, Pulse measurement, Rating of per diode | 0.55 | 0.65 | 0.75 |
| 反向峰值电流 Peak Reverse Current | I_{RRM} | mA | $V_{RM}=V_{RRM}$, 脉冲测试, 单个二极管的额定值 $V_{RM}=V_{RRM}$, Pulse measurement, Rating of per diode | 0.5 | | |
| 热阻 Thermal Resistance | $R_{\theta J-A}$ | $^\circ C/W$ | 结和环境之间, 安装在氧化铝基板上 Between junction and ambient, On alumina substrate | 76 | | |
| | | | 结和环境之间, 安装在玻璃-环氧基板上 Between junction and ambient, On glass-epoxy substrate | 134 | | |
| | $R_{\theta J-L}$ | | 结和引线之间 Between junction and lead | 20 | | |



■特性曲线（典型） Characteristics(Typical)

图1: Io-Ta曲线
FIG1:Io-Ta Curve

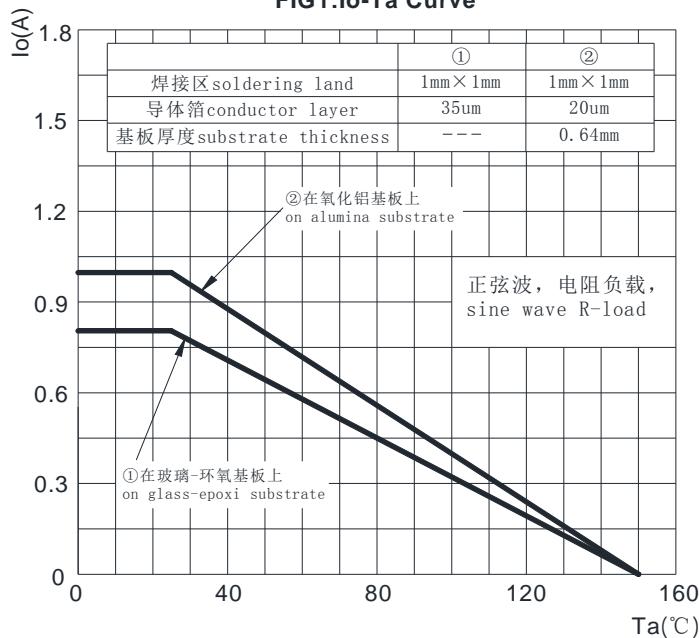


图2: 耐正向浪涌电流曲线
FIG2: Surge Forward Current Capability

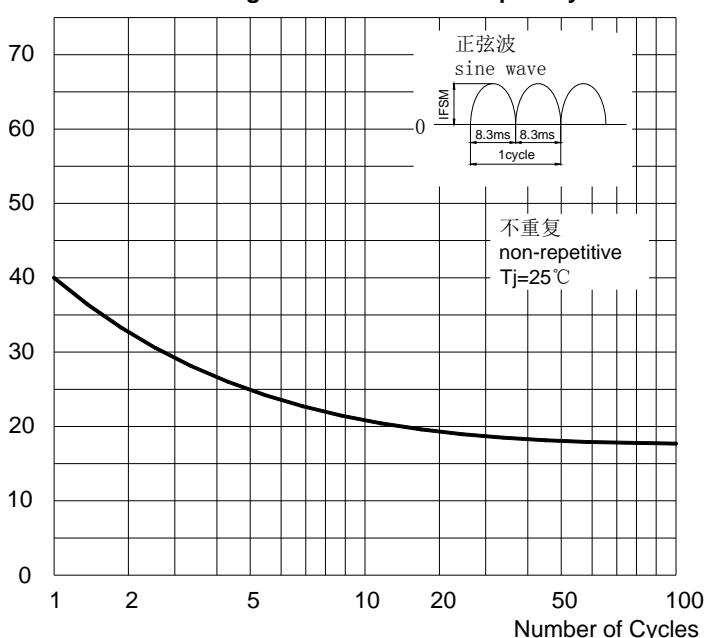


图3: 正向电压曲线
FIG3: Forward Voltage

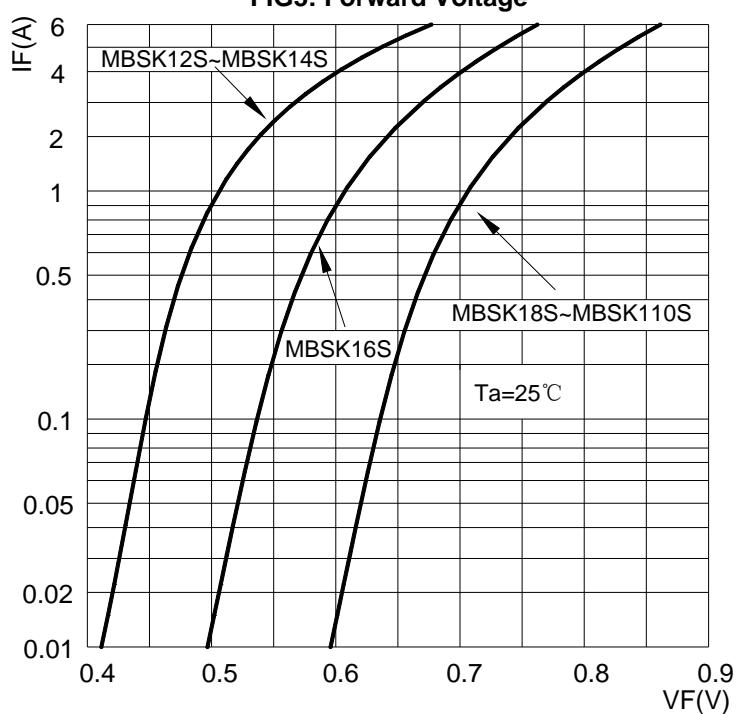


图4: 反向电流曲线
FIG4:Typical Reverse Characteristics

